

NEC

6, 8 PIN DIP 250 V BREAK DOWN VOLTAGE NORMALLY CLOSED TYPE 1-CH, 2-CH OPTICAL COUPLED MOSFET

PS7122A-1B, -2B
PS7122AL-1B, -2B

FEATURES

- **1 CHANNEL TYPE:**
1b Output
- **2 CHANNEL TYPE:**
1b + 1b Output
- **DESIGNED FOR AC/DC SWITCHING LINE CHANGER**
- **SMALL AND THIN PACKAGE:**
6, 8 PIN DIP
- **LOW LED OPERATING CURRENT:**
 $I_F = 2 \text{ mA}$
- **LOW OFFSET VOLTAGE**
- **SURFACE MOUNT AVAILABLE**

DESCRIPTION

PS7122A-1B, -2B and PS7122AL-1B, -2B are solid state relays containing a GaAs LED on the light emitting side (input side) and normally close (N.C.) contact MOSFETs on the output side.

They are suitable for analog signal control because of their low offset and high linearity.

APPLICATIONS

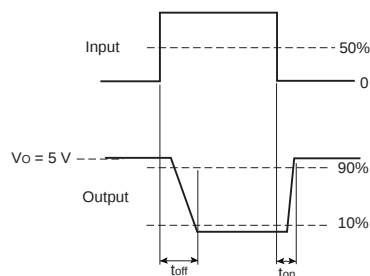
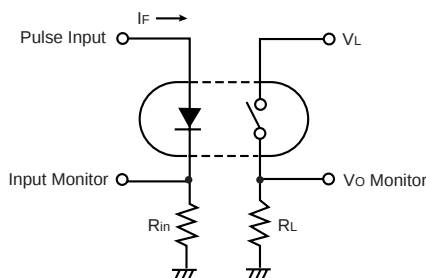
- **EXCHANGE EQUIPMENT**
- **MEASUREMENT EQUIPMENT**
- **FA/OA EQUIPMENT**

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$)

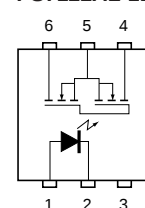
PART NUMBER					PS7122A-1B, -2B, PS7122AL-1B, -2B		
SYMBOLS		PARAMETERS		UNITS	MIN	TYP	MAX
Diode	V _F	Forward Voltage, I _F = 10 mA		V		1.2	1.4
	I _R	Reverse Current, V _R = 5 V		μA			5.0
MOSFET	I _{Loff}	Off-State Leakage Current, I _F = 10 mA, V _D = 250 V		μA		0.03	1.0
	C _{OUT}	Output Capacitance, I _F = 10 mA,, V = 0 V, f = 1 MHz		pF/ch		340	
Coupled	R _{on1}	On-State Resistance, I_F = 0 mA, I_L = 10 mA I_F = 0 mA, I_L = 200 mA, t_s10 ms		Ω		4.5	8.0
	R _{on2}						
	t _{on}	Turn-On Time ¹	I _F = 10 mA, V _L = 5 V, R _L = 500 Ω, PW ≥ 10 ms	ms		0.04	0.2
	t _{off}	Turn-Off Time ¹		ms		0.5	1.5
	R _{I-O}	Isolation Resistance, V _{in-out} = 1.0 kVDC		Ω	10 ⁹		
	C _{I-O}	Isolation Capacitance, V = 0 V, f = 1 MHz		pF/ch		1.1	

Note:

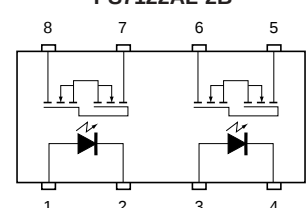
1. Turn-On, Turn-Off Time.



PS7122A-1B
PS7122AL-1B



PS7122A-2B
PS7122AL-2B

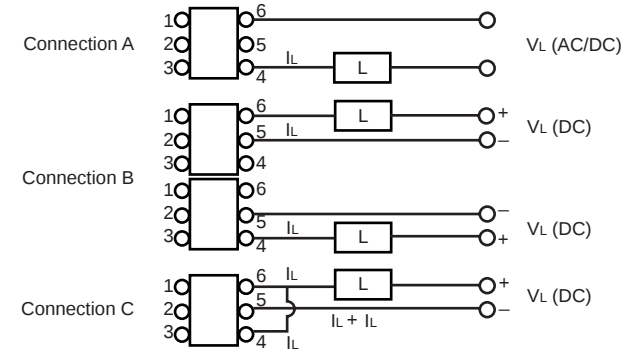


PS7122A-1B, -2B, PS7122AL-1B, -2B

ABSOLUTE MAXIMUM RATINGS¹ (T_A = 25°C)

SYMBOLS	PARAMETERS	UNITS	RATINGS	
			PS7122A-1B	PS7122A-2B
			PS7122AL-1B	PS7122AL-2B
Diode				
V _R	Reverse Voltage	V	5	
I _F	Forward Current (DC)	mA	50	
P _D	Power Dissipation	mW/ch	50	
I _F (Peak)	Peak Forward Current ²	A	1	
MOSFET				
V _L	Break Down Voltage	V	250	
I _L	Continuous Load Current ³	mA	200	
	Connection A		350	—
	Connection B			
	Connection C		500	—
I _{LP}	Pulse Load Current ⁴			
	AC/DC Connection			
P _D	Power Dissipation	mW/ch	560	375
Coupled				
B _V	Isolation Voltage ⁵	Vr.m.s.	1500	1500
P _T	Total Power Dissipation	mW	610	850
T _{STG}	Storage Temperature	°C	-40 to +100	-40 to +100
T _A	Operating Ambient Temp.	°C	-40 to +80	-40 to +80

- Notes:
1. Operation in excess of any one of these parameters may result in permanent damage.
 2. PW = 100 μs, Duty Cycle = 1 %
 3. Conditions: I_F ≥ 2 mA. The following types of load connections are available:



4. PW = 100 ms, 1 shot.
5. AC voltage for 1 minute at T_A = 25 °C, RH = 60 % between input and output.

RECOMMENDED
OPERATING CONDITIONS (T_A = 25 °C)

SYMBOL	PARAMETER	UNITS	MIN	TYP	MAX
I _F	LED Operating Current	mA	2	10	20
V _F	LED Off Voltage	V	0		0.5

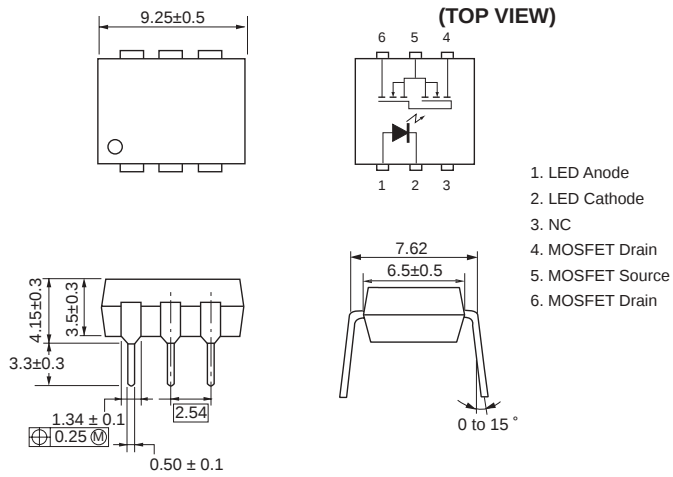
OUTLINE DIMENSIONS (Units in mm)

ORDERING INFORMATION

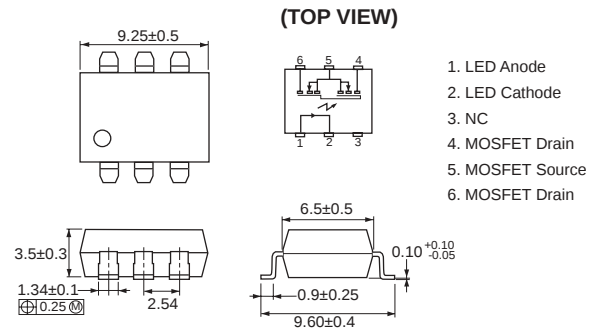
PART NUMBER	PACKAGE	PACKING STYLE
PS7122A-1B PS7122AL-1B	6-pin DIP	Magazine case 50 pcs
PS7122AL-1B-E3 PS7122AL-1B-E4		Embossed tape 1000 pcs/reel
PS7122A-2B PS7122AL-2B	8-pin DIP	Magazine case 50 pcs
PS7122AL-2B-E3 PS7122AL-2B-E4		Embossed tape 1000 pcs/reel

OUTLINE DIMENSIONS (Units in mm)

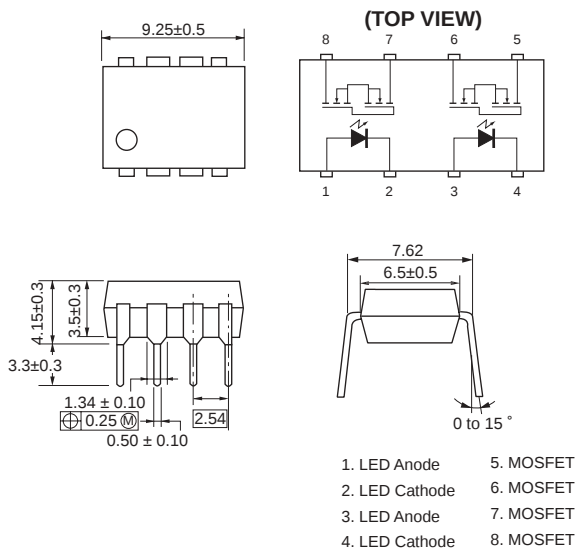
PS7122A-1B



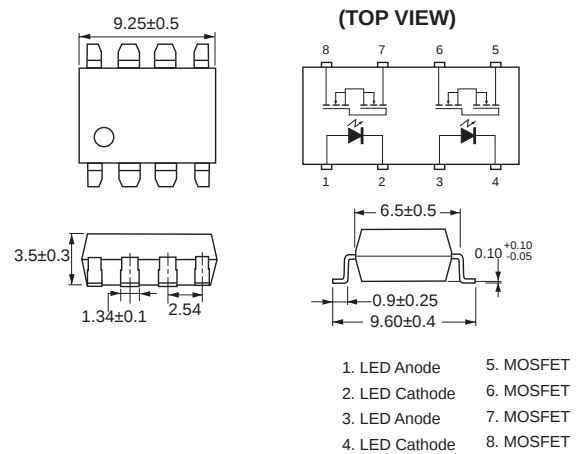
PS7122AL-1B



PS7122A-2B

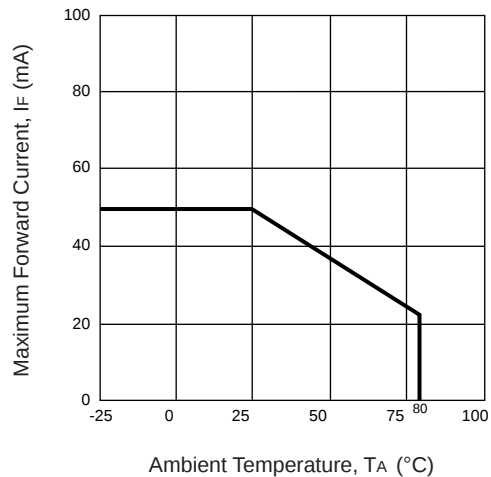


PS7522AL-2B

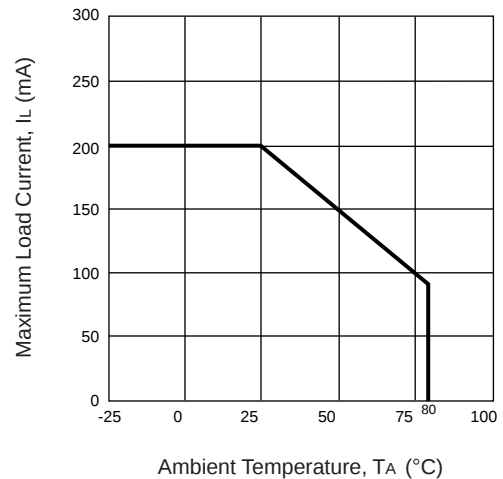


TYPICAL PERFORMANCE CURVES (T_A = 25 °C)

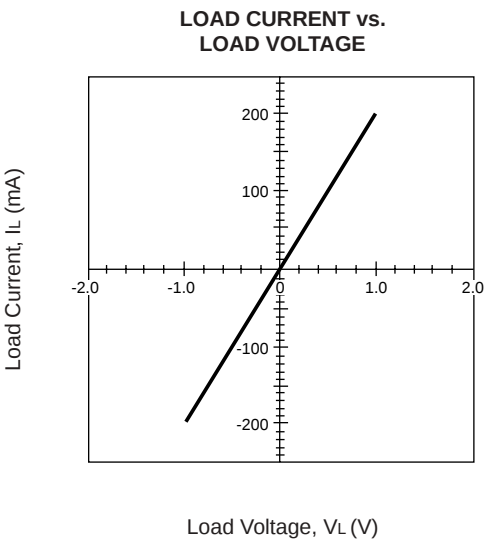
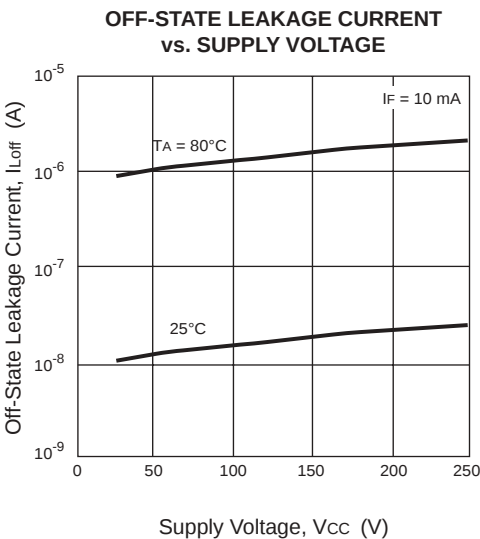
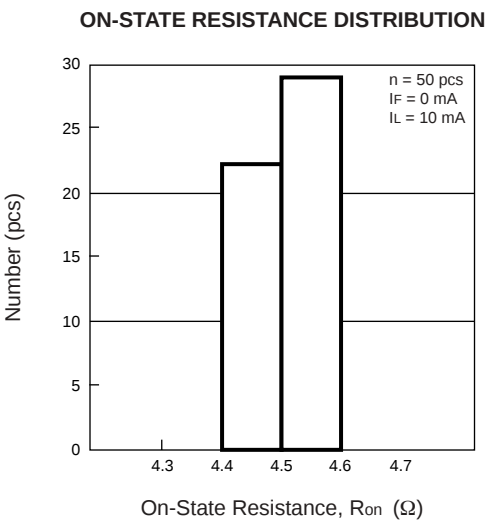
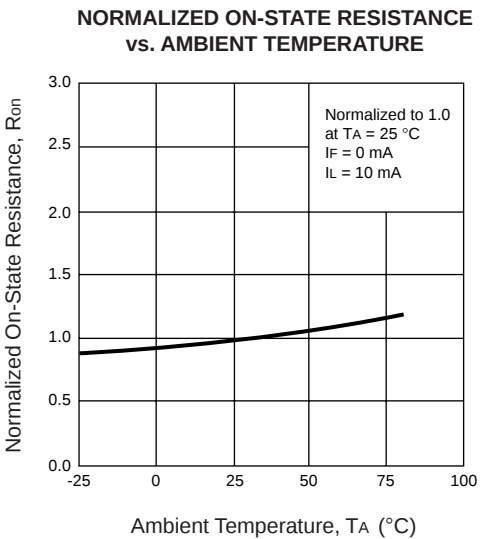
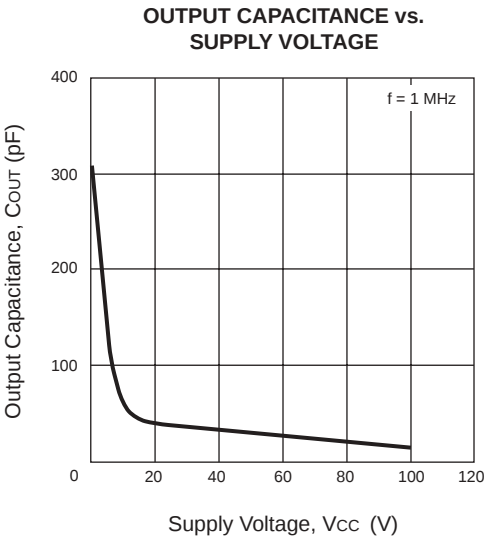
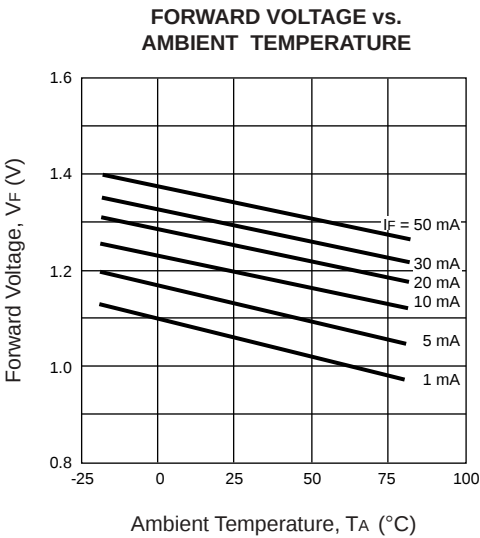
MAXIMUM FORWARD CURRENT vs. AMBIENT TEMPERATURE



MAXIMUM LOAD CURRENT vs. AMBIENT TEMPERATURE

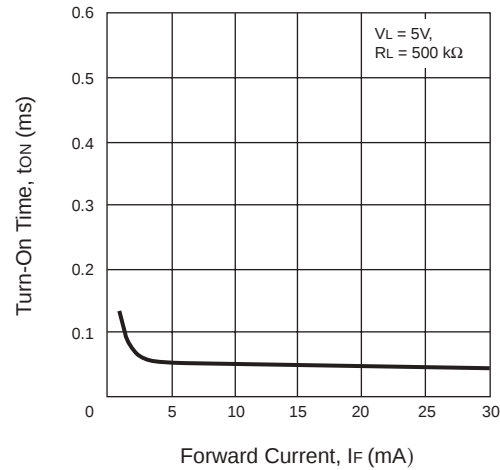


TYPICAL PERFORMANCE CURVES (TA = 25 °C)

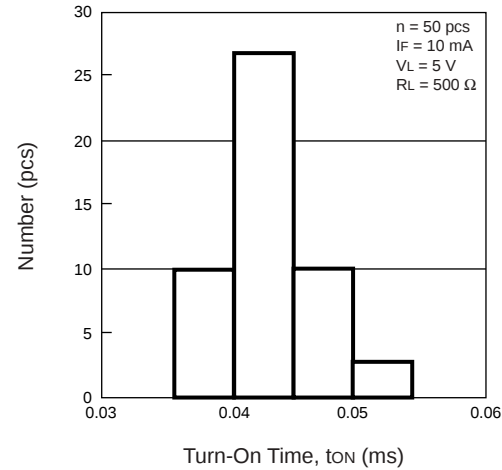


TYPICAL PERFORMANCE CURVES (T_A = 25 °C)

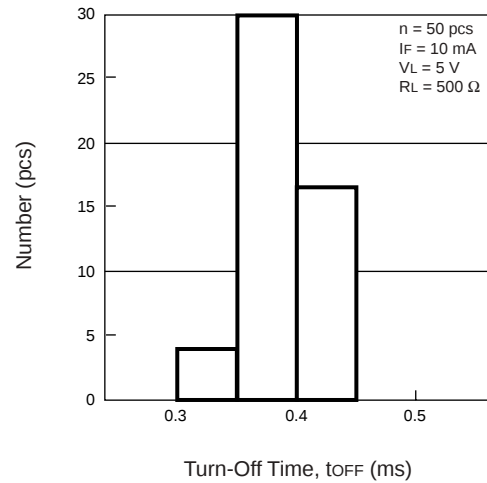
TURN-ON TIME vs.
FORWARD CURRENT



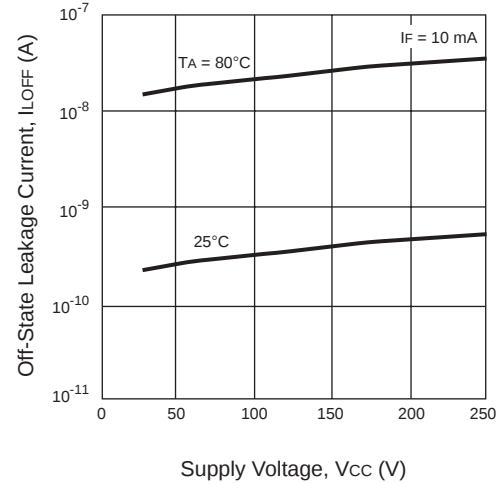
TURN-ON TIME DISTRIBUTION



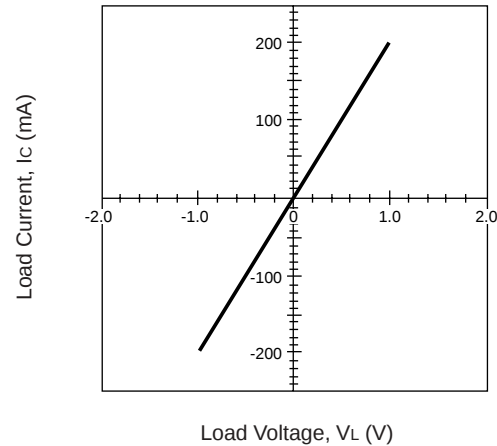
TURN-OFF TIME DISTRIBUTION



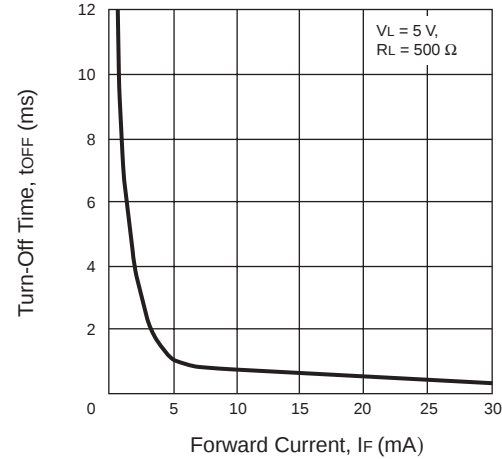
OFF-STATE LEAKAGE CURRENT
vs. SUPPLY VOLTAGE



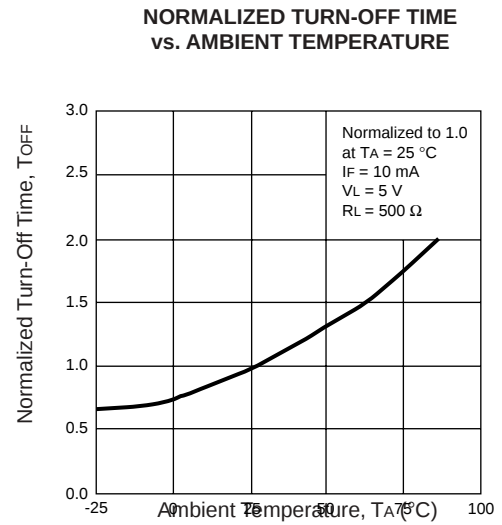
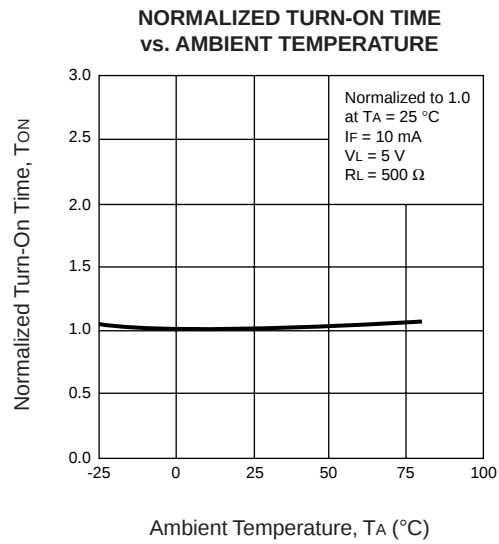
LOAD CURRENT vs.
LOAD VOLTAGE



TURN-OFF TIME vs.
FORWARD CURRENT

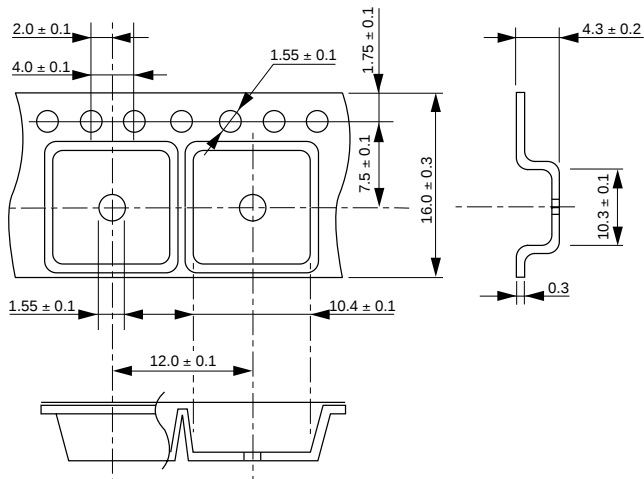


TYPICAL PERFORMANCE CURVES (T_A = 25 °C)

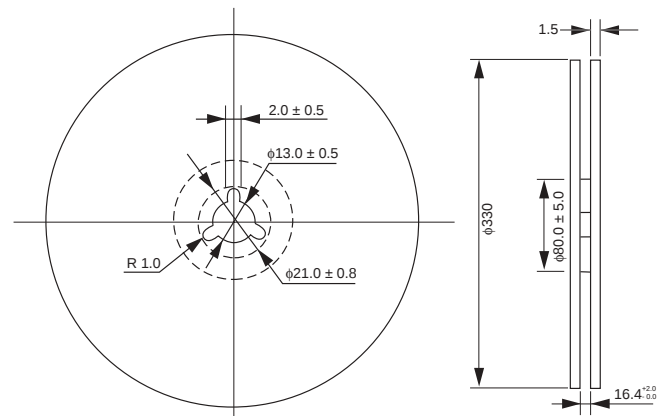


TAPING SPECIFICATIONS (Units in mm)

OUTLINE AND DIMENSIONS (TAPE)

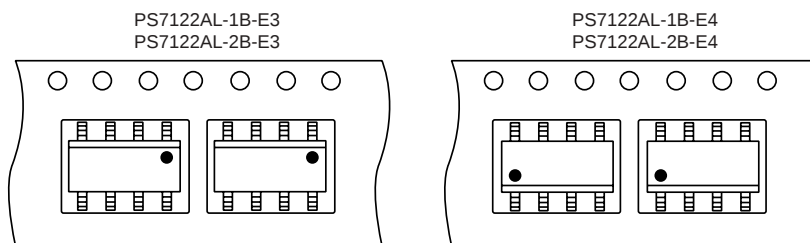


OUTLINE AND DIMENSIONS (REEL)



Notes:
1. Packing : 1000 pcs/reel

TAPING DIRECTION

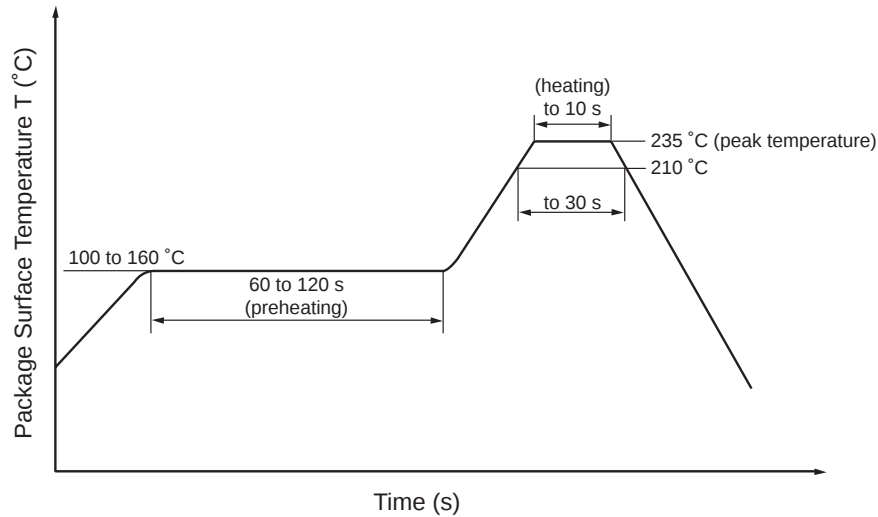


RECOMMENDED SOLDERING CONDITIONS

(1) Infrared reflow soldering

- Peak reflow temperature 235 °C or below (package surface temperature)
- Time of temperature higher than 210 °C 30 seconds or less
- Number of reflows Two
- Flux Rosin flux containing small amount of chlorine
(The flux with a maximum chlorine content of 0.2 Wt % is recommended.)

Recommended Temperature Profile of Infrared Reflow



(2) Dip soldering

- Temperature 260 °C or below (molten solder temperature)
- Time 10 seconds or less
- Number of times One
- Flux Rosin flux containing small amount of chlorine
(The flux with a maximum chlorine content of 0.2 Wt % is recommended.)

(3) Cautions

- Fluxes
Avoid removing the residual flux with freon-based cleaning solvent.

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